NSN 5962-01-330-5534

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-330-5534

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|---|
| Body Length: |
| Between 0.540 inches and 0.560 inches |
| Body Width: |
| Between 0.442 inches and 0.458 inches |
| Body Height: |
| Between 0.060 inches and 0.120 inches |
| Maximum Power Dissipation Rating: |
| 1.0 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| W/enable and w/inhibit and monolithic and erasable and programmable |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Leadless flat pack |
| Output Logic Form: |
| Complementary-metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 24 input |
| Case Outline Source And Designator: |
| C-12 mil-m-38510 |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| 6.25 volts power source |
| Memory Device Type: |
| Rom |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 32 leadless |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| - |
| Demilitarization: |
| Yes - demil/mli |

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